

CMOS Digital Integrated Circuits Silicon Monolithic

# TC7SZ02F

#### 1. Functional Description

· 2-Input NOR Gate

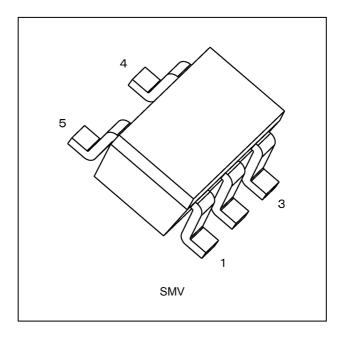
#### 2. Features

- (1) AEC-Q100 (Rev. H) (Note 1)
- (2) Wide operating temperature range:  $T_{opr} = -40$  to 125 °C (Note 2)
- (3) High output current:  $\pm 24$  mA (min) at  $V_{CC} = 3.0$  V
- (4) Super high speed operation:  $t_{pd} = 2.4$  ns (typ.) at  $V_{CC} = 5.0$  V,  $C_L = 50$  pF
- (5) Operation voltage range:  $V_{CC} = 1.65$  to 5.5 V
- (6) 5.5 V tolerant inputs
- (7) 5.5 V power down protection output
- (8) Matches the performance of TC74LCX series when operated at 3.3 V  $V_{\rm CC}$

Note 1: This device is compliant with the reliability requirements of AEC-Q100. For details, contact your Toshiba sales representative.

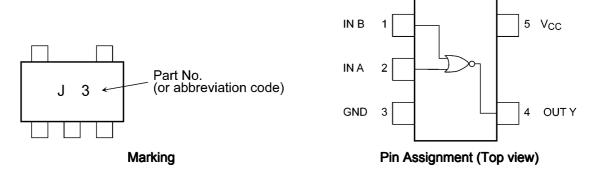
Note 2: For devices with the ordering part number ending in J(CT.  $T_{opr}$  = -40 to 85 °C for the other devices.

### 3. Packaging





#### 4. Marking and Pin Assignment



## 5. IEC Logic Symbol



#### 6. Truth Table

| А | В | Y |
|---|---|---|
| L | L | Н |
| L | Н | L |
| Н | L | L |
| Н | Н | L |

## 7. Absolute Maximum Ratings (Note) (Unless otherwise specified, Ta = 25 °C)

| Characteristics                 | Symbol           | Note     | Rating                        | Unit |
|---------------------------------|------------------|----------|-------------------------------|------|
| Supply voltage                  | V <sub>CC</sub>  |          | -0.5 to 6.0                   | V    |
| Input voltage                   | V <sub>IN</sub>  |          | -0.5 to 6.0                   | V    |
| DC output voltage               | V <sub>OUT</sub> | (Note 1) | -0.5 to 6.0                   | V    |
|                                 |                  | (Note 2) | -0.5 to V <sub>CC</sub> + 0.5 |      |
| Input diode current             | I <sub>IK</sub>  |          | -20                           | mA   |
| Output diode current            | I <sub>OK</sub>  | (Note 3) | -20                           | mA   |
| DC output current               | I <sub>OUT</sub> |          | ±50                           | mA   |
| V <sub>CC</sub> /ground current | I <sub>CC</sub>  |          | ±50                           | mA   |
| Power dissipation               | P <sub>D</sub>   |          | 200                           | mW   |
| Storage temperature             | T <sub>stg</sub> |          | -65 to 150                    | °C   |

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1:  $V_{CC} = 0 V$ 

Note 2: High (H) or Low (L) state. I<sub>OUT</sub> absolute maximum rating must be observed.

Note 3: V<sub>OUT</sub> < GND



### 8. Operating Ranges (Note)

| Characteristics          | Symbol           | Note     | Test Condition                       | Rating               | Unit |
|--------------------------|------------------|----------|--------------------------------------|----------------------|------|
| Supply voltage           | V <sub>CC</sub>  |          | _                                    | 1.65 to 5.5          | V    |
|                          |                  | (Note 1) | _                                    | 1.5 to 5.5           |      |
| Input voltage            | V <sub>IN</sub>  |          | _                                    | 0 to 5.5             | V    |
| Output voltage           | V <sub>OUT</sub> | (Note 2) | _                                    | 0 to 5.5             | V    |
|                          |                  | (Note 3) | _                                    | 0 to V <sub>CC</sub> |      |
| Operating temperature    | T <sub>opr</sub> | (Note 4) | _                                    | -40 to 125           | °C   |
|                          |                  | (Note 5) | _                                    | -40 to 85            |      |
| Input rise and fall time | dt/dv            |          | $V_{CC}$ = 1.8 ± 0.15 V, 2.5 ± 0.2 V | 0 to 20              | ns/V |
|                          |                  |          | V <sub>CC</sub> = 3.3 ± 0.3 V        | 0 to 10              | ]    |
|                          |                  |          | V <sub>CC</sub> = 5.0 ± 0.5 V        | 0 to 5               | ]    |

Note: The operating ranges must be maintained to ensure the normal operation of the device.

Unused inputs must be tied to either  $V_{CC}$  or GND.

Note 1: Data retention only

Note 2:  $V_{CC} = 0 V$ 

Note 3: High (H) or Low (L) state.

Note 4: For devices with the ordering part number ending in J(CT.

Note 5: For devices except those with the ordering part number ending in J(CT.

#### 9. Electrical Characteristics

## 9.1. DC Characteristics (Unless otherwise specified, T<sub>a</sub> = 25 °C)

| Characteristics           | Symbol           | Test Condition                                       |                           | V <sub>CC</sub> (V) | Min                    | Тур. | Max                    | Unit |
|---------------------------|------------------|--|---------------------------|---------------------|------------------------|------|------------------------|------|
| High-level input voltage  | V <sub>IH</sub>  | _  |                           | 1.65 to<br>1.95     | V <sub>CC</sub> × 0.88 | _    | _                      | V    |
|                           |                  |  |                           | 2.3 to 5.5          | V <sub>CC</sub> × 0.75 | _    | _                      |      |
| Low-level input voltage   | V <sub>IL</sub>  | _  |                           | 1.65 to<br>1.95     | _                      | _    | V <sub>CC</sub> × 0.12 | ٧    |
|                           |                  |  |                           | 2.3 to 5.5          | _                      | _    | $V_{CC} \times 0.25$   |      |
| High-level output voltage | V <sub>OH</sub>  | V <sub>IN</sub> = V <sub>IL</sub>                    | I <sub>OH</sub> = -100 μA | 1.65                | 1.55                   | 1.65 | _                      | ٧    |
|                           |                  |  |                           | 2.3                 | 2.2                    | 2.3  | _                      |      |
|                           |                  |  |                           | 3.0                 | 2.9                    | 3.0  | _                      |      |
|                           |                  |  |                           | 4.5                 | 4.4                    | 4.5  | _                      |      |
|                           |                  |  | I <sub>OH</sub> = -8 mA   | 2.3                 | 1.9                    | 2.15 | _                      |      |
|                           |                  |  | I <sub>OH</sub> = -16 mA  | 3.0                 | 2.4                    | 2.8  | _                      |      |
|                           |                  |  | I <sub>OH</sub> = -24 mA  | 3.0                 | 2.3                    | 2.68 | _                      |      |
|                           |                  |  | I <sub>OH</sub> = -32 mA  | 4.5                 | 3.8                    | 4.2  | _                      |      |
| Low-level output voltage  | V <sub>OL</sub>  | V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> | I <sub>OL</sub> = 100 μA  | 1.65                | _                      | 0.0  | 0.1                    | V    |
|                           |                  |  |                           | 2.3                 | _                      | 0.0  | 0.1                    |      |
|                           |                  |  |                           | 3.0                 | _                      | 0.0  | 0.1                    |      |
|                           |                  |  |                           | 4.5                 | _                      | 0.0  | 0.1                    |      |
|                           |                  |  | I <sub>OL</sub> = 8 mA    | 2.3                 | _                      | 0.1  | 0.3                    |      |
|                           |                  |  | I <sub>OL</sub> = 16 mA   | 3.0                 | _                      | 0.15 | 0.4                    |      |
|                           |                  |  | I <sub>OL</sub> = 24 mA   | 3.0                 | _                      | 0.22 | 0.55                   |      |
|                           |                  |  | I <sub>OL</sub> = 32 mA   | 4.5                 | _                      | 0.22 | 0.55                   |      |
| Input leakage current     | I <sub>IN</sub>  | V <sub>IN</sub> = 5.5 V or GND                       |                           | 0 to 5.5            | _                      | _    | ±1.0                   | μА   |
| Power-OFF leakage current | I <sub>OFF</sub> | V <sub>IN</sub> or V <sub>OUT</sub> = 5.5 V          |                           | 0                   | _                      | _    | 1                      | μА   |
| Quiescent supply current  | I <sub>CC</sub>  | V <sub>IN</sub> = V <sub>CC</sub> or GND             |                           | 5.5                 | _                      | _    | 2                      | μА   |



# 9.2. DC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C)

| Characteristics           | Symbol           | Test Condition                                       |                           | V <sub>CC</sub> (V) | Min                    | Max                    | Unit |
|---------------------------|------------------|--|---------------------------|---------------------|------------------------|------------------------|------|
| High-level input voltage  | V <sub>IH</sub>  | _  |                           | 1.65 to<br>1.95     | V <sub>CC</sub> × 0.88 | _                      | V    |
|                           |                  |  |                           | 2.3 to 5.5          | V <sub>CC</sub> × 0.75 | _                      |      |
| Low-level input voltage   | V <sub>IL</sub>  | _  |                           | 1.65 to<br>1.95     | _                      | V <sub>CC</sub> × 0.12 | V    |
|                           |                  |  |                           | 2.3 to 5.5          | _                      | V <sub>CC</sub> × 0.25 |      |
| High-level output voltage | V <sub>OH</sub>  | $V_{IN} = V_{IL}$                                    | I <sub>OH</sub> = -100 μA | 1.65                | 1.55                   | _                      | ٧    |
|                           |                  |  |                           | 2.3                 | 2.2                    | _                      |      |
|                           |                  |  |                           | 3.0                 | 2.9                    | _                      |      |
|                           |                  |  |                           | 4.5                 | 4.4                    | _                      |      |
|                           |                  |  | I <sub>OH</sub> = -8 mA   | 2.3                 | 1.9                    | _                      |      |
|                           |                  |  | I <sub>OH</sub> = -16 mA  | 3.0                 | 2.4                    | _                      |      |
|                           |                  |  | I <sub>OH</sub> = -24 mA  | 3.0                 | 2.3                    | _                      |      |
|                           |                  |  | I <sub>OH</sub> = -32 mA  | 4.5                 | 3.8                    | _                      |      |
| Low-level output voltage  | V <sub>OL</sub>  | V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> | I <sub>OL</sub> = 100 μA  | 1.65                | _                      | 0.1                    | V    |
|                           |                  |  |                           | 2.3                 | _                      | 0.1                    |      |
|                           |                  |  |                           | 3.0                 | _                      | 0.1                    |      |
|                           |                  |  |                           | 4.5                 | _                      | 0.1                    |      |
|                           |                  |  | I <sub>OL</sub> = 8 mA    | 2.3                 | _                      | 0.3                    |      |
|                           |                  |  | I <sub>OL</sub> = 16 mA   | 3.0                 | _                      | 0.4                    |      |
|                           |                  |  | I <sub>OL</sub> = 24 mA   | 3.0                 | _                      | 0.55                   |      |
|                           |                  |  | I <sub>OL</sub> = 32 mA   | 4.5                 | _                      | 0.55                   |      |
| Input leakage current     | I <sub>IN</sub>  | V <sub>IN</sub> = 5.5 V or GND                       |                           | 0 to 5.5            | _                      | ±10.0                  | μΑ   |
| Power-OFF leakage current | I <sub>OFF</sub> | V <sub>IN</sub> or V <sub>OUT</sub> = 5.5 V          |                           | 0                   | _                      | 10                     | μΑ   |
| Quiescent supply current  | I <sub>CC</sub>  | V <sub>IN</sub> = V <sub>CC</sub> or GND             |                           | 5.5                 | _                      | 20                     | μΑ   |



# 9.3. DC Characteristics (Note) (Unless otherwise specified, T<sub>a</sub> = -40 to 125 °C)

| Characteristics           | Symbol           | Test Condition                                       |                           | V <sub>CC</sub> (V) | Min                    | Max                    | Unit |
|---------------------------|------------------|--|---------------------------|---------------------|------------------------|------------------------|------|
| High-level input voltage  | V <sub>IH</sub>  | _  |                           | 1.65 to<br>1.95     | V <sub>CC</sub> × 0.88 | _                      | V    |
|                           |                  |  |                           | 2.3 to 5.5          | $V_{CC} \times 0.75$   | _                      |      |
| Low-level input voltage   | V <sub>IL</sub>  | _  |                           | 1.65 to<br>1.95     | _                      | V <sub>CC</sub> × 0.12 | V    |
|                           |                  |  |                           | 2.3 to 5.5          | _                      | V <sub>CC</sub> × 0.25 |      |
| High-level output voltage | V <sub>OH</sub>  | $V_{IN} = V_{IL}$                                    | I <sub>OH</sub> = -100 μA | 1.65                | 1.55                   | _                      | V    |
|                           |                  |  |                           | 2.3                 | 2.2                    | _                      |      |
|                           |                  |  |                           | 3.0                 | 2.9                    | _                      |      |
|                           |                  |  |                           | 4.5                 | 4.4                    | _                      |      |
|                           |                  |  | I <sub>OH</sub> = -8 mA   | 2.3                 | 1.7                    | _                      |      |
|                           |                  |  | I <sub>OH</sub> = -16 mA  | 3.0                 | 2.2                    | _                      |      |
|                           |                  |  | I <sub>OH</sub> = -24 mA  | 3.0                 | 2.0                    | _                      |      |
|                           |                  |  | I <sub>OH</sub> = -32 mA  | 4.5                 | 3.4                    | _                      |      |
| Low-level output voltage  | V <sub>OL</sub>  | V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> | I <sub>OL</sub> = 100 μA  | 1.65                | _                      | 0.1                    | V    |
|                           |                  |  |                           | 2.3                 | _                      | 0.1                    |      |
|                           |                  |  |                           | 3.0                 | _                      | 0.1                    |      |
|                           |                  |  |                           | 4.5                 | _                      | 0.1                    |      |
|                           |                  |  | I <sub>OL</sub> = 8 mA    | 2.3                 | _                      | 0.45                   |      |
|                           |                  |  | I <sub>OL</sub> = 16 mA   | 3.0                 | _                      | 0.6                    |      |
|                           |                  |  | I <sub>OL</sub> = 24 mA   | 3.0                 | _                      | 0.8                    |      |
|                           |                  |  | I <sub>OL</sub> = 32 mA   | 4.5                 | _                      | 0.8                    |      |
| Input leakage current     | I <sub>IN</sub>  | V <sub>IN</sub> = 5.5 V or GND                       |                           | 0 to 5.5            | _                      | ±20.0                  | μΑ   |
| Power-OFF leakage current | I <sub>OFF</sub> | V <sub>IN</sub> or V <sub>OUT</sub> = 5.5 V          |                           | 0                   | _                      | 100                    | μΑ   |
| Quiescent supply current  | I <sub>CC</sub>  | $V_{IN} = V_{CC}$ or GND                             |                           | 5.5                 | _                      | 200                    | μА   |

Note: For devices with the ordering part number ending in J(CT.



## 9.4. AC Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 3$ ns)

| Characteristics        | Symbol                             | Note     | Test<br>Condition  | V <sub>CC</sub> (V) | C <sub>L</sub> (pF) | Min | Тур. | Max | Unit |
|------------------------|------------------------------------|----------|--------------------|---------------------|---------------------|-----|------|-----|------|
| Propagation delay time | t <sub>PLH</sub> ,t <sub>PHL</sub> |          | $R_L = 1 M\Omega$  | $1.8 \pm 0.15$      | 15                  | 2.0 | 4.4  | 9.5 | ns   |
|                        |                                    |          |                    | $2.5 \pm 0.2$       |                     | 0.8 | 2.9  | 6.5 |      |
|                        |                                    |          |                    | $3.3 \pm 0.3$       |                     | 0.5 | 2.3  | 4.5 |      |
|                        |                                    |          |                    | $5.0 \pm 0.5$       |                     | 0.5 | 1.9  | 3.9 |      |
|                        |                                    |          | $R_L = 500 \Omega$ | $3.3 \pm 0.3$       | 50                  | 1.5 | 2.9  | 5.0 | ns   |
|                        |                                    |          |                    | $5.0 \pm 0.5$       |                     | 0.8 | 2.4  | 4.3 |      |
| Input capacitance      | C <sub>IN</sub>                    |          | _                  | 0 to 5.5            | _                   | _   | 4    | _   | pF   |
| Power dissipation      | C <sub>PD</sub>                    | (Note 1) | _                  | 3.3                 | _                   | _   | 23   | _   | pF   |
| capacitance            |                                    |          |                    | 5.5                 |                     | _   | 30   | _   |      |

Note 1:  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.  $I_{CC(opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$ 

# 9.5. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C, Input: $t_r = t_f = 3$ ns)

| Characteristics        | Symbol                             | Test Condition       | V <sub>CC</sub> (V) | C <sub>L</sub> (pF) | Min | Max  | Unit |
|------------------------|------------------------------------|----------------------|---------------------|---------------------|-----|------|------|
| Propagation delay time | t <sub>PLH</sub> ,t <sub>PHL</sub> | $R_L = 1 M\Omega$    | 1.8 ± 0.15          | 15                  | 2.0 | 10.0 | ns   |
|                        |                                    |                      | $2.5 \pm 0.2$       |                     | 0.8 | 7.0  |      |
|                        |                                    |                      | $3.3 \pm 0.3$       |                     | 0.5 | 4.7  |      |
|                        |                                    |                      | 5.0 ± 0.5           |                     | 0.5 | 4.1  |      |
|                        |                                    | $R_L$ = 500 $\Omega$ | $3.3 \pm 0.3$       | 50                  | 1.5 | 5.2  | ns   |
|                        |                                    |                      | $5.0 \pm 0.5$       |                     | 0.8 | 4.5  |      |

# 9.6. AC Characteristics (Note) (Unless otherwise specified, $T_a = -40$ to 125 °C, Input: $t_f = t_f = 3$ ns)

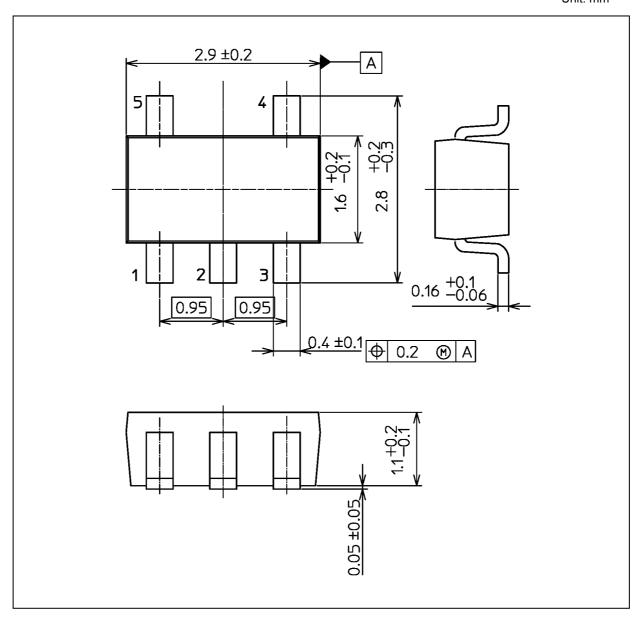
| Characteristics        | Symbol                             | Test Condition       | V <sub>CC</sub> (V) | C <sub>L</sub> (pF) | Min | Max  | Unit |
|------------------------|------------------------------------|----------------------|---------------------|---------------------|-----|------|------|
| Propagation delay time | t <sub>PLH</sub> ,t <sub>PHL</sub> | $R_L = 1 M\Omega$    | 1.8 ± 0.15          | 15                  | 2.0 | 11.0 | ns   |
|                        |                                    |                      | $2.5 \pm 0.2$       |                     | 0.8 | 8.0  |      |
|                        |                                    |                      | $3.3 \pm 0.3$       |                     | 0.5 | 5.5  |      |
|                        |                                    |                      | 5.0 ± 0.5           |                     | 0.5 | 5.0  |      |
|                        |                                    | $R_L$ = 500 $\Omega$ | $3.3 \pm 0.3$       | 50                  | 1.5 | 6.0  | ns   |
|                        |                                    |                      | $5.0 \pm 0.5$       |                     | 0.8 | 5.0  |      |

Note: For devices with the ordering part number ending in J(CT.



## **Package Dimensions**

Unit: mm



Weight: 14 mg (typ.)

|               | Package Name(s) |
|---------------|-----------------|
| JEDEC: SOT-25 |                 |
| Nickname: SMV |                 |



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